Very Low Noise Quad Operational Amplifier

OP470

## FEATURES

Very Low-Noise, $5 \mathrm{nV} / \sqrt{\mathrm{Hz}}$ @ 1 kHz Max
Excellent Input Offset Voltage, 0.4 mV Max
Low Offset Voltage Drift, $2 \mu \mathrm{~V} /{ }^{\circ} \mathrm{C}$ Max
Very High Gain, 1000 V/mV Min
Outstanding CMR, 110 dB Min
Slew Rate, 2 V/ $\mu \mathrm{s}$ Typ
Gain-Bandwidth Product, 6 MHz Typ
Industry Standard Quad Pinouts
Available in Die Form

## GENERAL DESCRIPTION

The OP470 is a high-performance monolithic quad operational amplifier with exceptionally low voltage noise, $5 \mathrm{nV} / \sqrt{\mathrm{Hz}}$ at 1 kHz max, offering comparable performance to ADI's industry standard OP27.
The OP470 features an input offset voltage below 0.4 mV , excellent for a quad op amp, and an offset drift under $2 \mu \mathrm{~V} /{ }^{\circ} \mathrm{C}$, guaranteed over the full military temperature range. Open loop gain of the OP470 is over $1,000,000$ into a $10 \mathrm{k} \Omega$ load ensuring excellent gain accuracy and linearity, even in high gain applications. Input bias current is under 25 nA , which reduces errors due to signal source resistance. The OP470's CMR of over 110 dB and PSRR of less than $1.8 \mu \mathrm{~V} / \mathrm{V}$ significantly reduce errors due to ground noise and power supply fluctuations. Power consumption of the quad OP470 is half that of four OP27s, a significant advantage for power conscious applications. The OP470 is unity-gain stable with a gain bandwidth product of 6 MHz and a slew rate of $2 \mathrm{~V} / \mu \mathrm{s}$.

## PIN CONNECTIONS



16-Lead SOIC Package (S-Suffix)


The OP470 offers excellent amplifier matching which is important for applications such as multiple gain blocks, low noise instrumentation amplifiers, quad buffers, and low noise active filters.
The OP470 conforms to the industry standard 14-lead DIP pinout. It is pin compatible with the LM148/149, HA4741, HA5104, and RM4156 quad op amps and can be used to upgrade systems using these devices.
For higher speed applications, the OP471, with a slew rate of 8 $\mathrm{V} / \mu \mathrm{s}$, is recommended.

## SIMPLIFIED SCHEMATIC



REV. B

[^0] under any patent or patent rights of Analog Devices.

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OP470-SPECIFICATIONS
ELECTRICAL CHARACTERISTICS (at $_{s}= \pm 15 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$, unless otherwise noted.)

|  |  |  | OP470A/E |  |  | OP470F |  |  | OP470G |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Parameter | Symbol | Conditions | Min | Typ | Max | Min | Typ | Max | Min | Typ | Max | Unit |
| INPUT OFFSET VOLTAGE | $\mathrm{V}_{\mathrm{OS}}$ |  |  | 0.1 | 0.4 |  | 0.2 | 0.8 |  | 0.4 | 1.0 | mV |
| INPUT OFFSET CURRENT | $\mathrm{I}_{\text {OS }}$ | $\mathrm{V}_{\mathrm{CM}}=0 \mathrm{~V}$ |  | 3 | 10 |  | 6 | 20 |  | 12 | 30 | nA |
| INPUT BIAS CURRENT | $\mathrm{I}_{\mathrm{B}}$ | $\mathrm{V}_{\mathrm{CM}}=0 \mathrm{~V}$ |  | 6 | 25 |  | 15 | 50 |  | 25 | 60 | nA |
| INPUT NOISE VOLTAGE | $\mathrm{e}_{\mathrm{np} \text {-p }}$ | $\begin{aligned} & 0.1 \mathrm{~Hz} \text { to } 10 \mathrm{~Hz} \\ & \text { (Note 1) } \end{aligned}$ |  | 80 | 200 |  | 80 | 200 |  | 80 | 200 | nV p-p |
| INPUT NOISE <br> Voltage Density | $\mathrm{e}_{\mathrm{n}}$ | $\begin{aligned} & \mathrm{f}_{\mathrm{O}}=10 \mathrm{~Hz} \\ & \mathrm{f}_{\mathrm{O}}=100 \mathrm{~Hz} \\ & \mathrm{f}_{\mathrm{O}}=1 \mathrm{kHz} \\ & \text { (Note 2) } \end{aligned}$ |  | $\begin{aligned} & 3.8 \\ & 3.3 \\ & 3.2 \end{aligned}$ | $\begin{aligned} & 6.5 \\ & 5.5 \\ & 5.0 \end{aligned}$ |  | $\begin{aligned} & 3.8 \\ & 3.3 \\ & 3.2 \end{aligned}$ | $\begin{aligned} & 6.5 \\ & 5.5 \\ & 5.0 \end{aligned}$ |  | $\begin{aligned} & 3.8 \\ & 3.3 \\ & 3.2 \end{aligned}$ | $\begin{aligned} & 6.5 \\ & 5.5 \\ & 5.0 \end{aligned}$ | $\mathrm{nV} \sqrt{\mathrm{Hz}}$ |
| INPUT NOISE Current Density | $\mathrm{i}_{\mathrm{n}}$ | $\begin{aligned} \mathrm{f}_{\mathrm{O}} & =10 \mathrm{~Hz} \\ \mathrm{f}_{\mathrm{O}} & =100 \mathrm{~Hz} \\ \mathrm{f}_{\mathrm{O}} & =1 \mathrm{kHz} \end{aligned}$ |  | $\begin{aligned} & 1.7 \\ & 0.7 \\ & 0.4 \end{aligned}$ |  |  | $\begin{aligned} & 1.7 \\ & 0.7 \\ & 0.4 \end{aligned}$ |  |  | $\begin{aligned} & 1.7 \\ & 07 \\ & 0.4 \end{aligned}$ |  | $\mathrm{pA} \sqrt{\overline{\mathrm{Hz}}}$ |
| LARGE-SIGNAL <br> Voltage Gain | $\mathrm{A}_{\mathrm{vo}}$ | $\begin{aligned} & \mathrm{V}= \pm 10 \mathrm{~V} \\ & \mathrm{R}_{\mathrm{L}}=10 \mathrm{k} \Omega \\ & \mathrm{R}_{\mathrm{L}}=2 \mathrm{k} \Omega \end{aligned}$ | $\begin{aligned} & 1000 \\ & 500 \end{aligned}$ | $\begin{aligned} & 2300 \\ & 1200 \end{aligned}$ |  | $\begin{aligned} & 800 \\ & 400 \end{aligned}$ | $\begin{aligned} & 1700 \\ & 900 \end{aligned}$ |  | $\begin{aligned} & 800 \\ & 400 \end{aligned}$ | $\begin{aligned} & 1700 \\ & 900 \end{aligned}$ |  | $\mathrm{V} / \mathrm{mV}$ |
| INPUT VOLTAGE RANGE | IVR | (Note 3) | $\pm 11$ | $\pm 12$ |  | $\pm 11$ | $\pm 12$ |  | $\pm 11$ | $\pm 12$ |  | V |
| OUTPUT VOLTAGE SWING | $\mathrm{V}_{\mathrm{O}}$ | $\mathrm{R}_{\mathrm{L}} \geq 2 \mathrm{k} \Omega$ | $\pm 12$ | $\pm 13$ |  | $\pm 12$ | $\pm 13$ |  | $\pm 12$ | $\pm 13$ |  | V |
| COMMON-MODE REJECTION | CMR | $\mathrm{V}_{\mathrm{CM}}= \pm 11 \mathrm{~V}$ | 110 | 125 |  | 100 | 120 |  | 100 | 120 |  | dB |
| POWER SUPPLY REJECTION RATIO | PSRR | $\mathrm{V}_{\mathrm{S}}= \pm 4.5 \mathrm{~V}$ to $\pm 18 \mathrm{~V}$ |  | 0.56 | 1.8 |  | 1.0 | 5.6 |  | 1.0 | 5.6 | $\mu \mathrm{V} / \mathrm{V}$ |
| SLEW RATE | SR |  | 1.4 | 2 |  | 1.4 | 2 |  | 1.4 | 2 |  | V/ $\mu \mathrm{s}$ |
| SUPPLY CURRENT <br> (All Amplifiers) | $\mathrm{I}_{\text {SY }}$ | No Load |  | 9 | 11 |  | 9 | 11 |  | 9 | 11 | mA |
| GAIN BANDWIDTH PRODUCT | GBW | $\mathrm{A}_{\mathrm{V}}=10$ |  | 6 |  |  | 6 |  |  | 6 |  | MHz |
| CHANNEL SEPARATION | CS | $\begin{aligned} & \mathrm{V}_{\mathrm{O}}=20 \mathrm{~V} \text { p-p } \\ & \left.\mathrm{f}_{\mathrm{O}}=10 \mathrm{~Hz} \text { (Note } 1\right) \end{aligned}$ | 125 | 155 |  | 125 | 155 |  | 125 | 155 |  | dB |
| INPUT <br> CAPACITANCE | $\mathrm{C}_{\text {IN }}$ |  |  | 2 |  |  | 2 |  |  | 2 |  | pF |
| INPUT RESISTANCE Differential-Mode | $\mathrm{R}_{\text {IN }}$ |  |  | 0.4 |  |  | 0.4 |  |  | 0.4 |  | $\mathrm{M} \Omega$ |
| INPUT RESISTANCE Common-Mode | $\mathrm{R}_{\mathrm{INCM}}$ |  |  | 11 |  |  | 11 |  |  | 11 |  | $\mathrm{G} \Omega$ |
| SETTLING TIME | $\mathrm{t}_{\text {S }}$ | $\begin{aligned} & \mathrm{A}_{\mathrm{V}}=1 \\ & \text { to } 0.1 \% \\ & \text { to } 0.01 \% \end{aligned}$ |  | $\begin{aligned} & 5.5 \\ & 6.0 \end{aligned}$ |  |  | $\begin{aligned} & 5.5 \\ & 6.0 \end{aligned}$ |  |  | $\begin{aligned} & 5.5 \\ & 6.0 \end{aligned}$ |  | $\mu \mathrm{s}$ |

## NOTES

${ }^{1}$ Guaranteed but not $100 \%$ tested
${ }^{2}$ Sample tested
${ }^{3}$ Guaranteed by CMR test

ELECTRICAL CHARACTERISTICS (at $\mathrm{V}_{\mathrm{s}}= \pm 15 \mathrm{~V},-55^{\circ} \leq \leq \mathrm{I}_{\mathrm{A}} \leq 125^{\circ}$ for or op470, unless otherwise noted.)

| Parameter | Symbol | Conditions | OP470A |  |  | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | Min | Typ | Max |  |
| INPUT OFFSET VOLTAGE | $\mathrm{V}_{\text {Os }}$ |  |  | 0.14 | 0.6 | mV |
| AVERAGE INPUT Offset Voltage Drift | $\mathrm{TCV}_{\text {Os }}$ |  |  | 0.4 | 2 | $\mu \mathrm{V} /{ }^{\circ} \mathrm{C}$ |
| INPUT OFFSET CURRENT | $\mathrm{I}_{\mathrm{OS}}$ | $\mathrm{V}_{\mathrm{CM}}=0 \mathrm{~V}$ |  | 5 | 20 | nA |
| INPUT BIAS CURRENT | $\mathrm{I}_{\mathrm{B}}$ | $\mathrm{V}_{\mathrm{CM}}=0 \mathrm{~V}$ |  | 15 | 20 | nA |
| LARGE-SIGNAL <br> Voltage Gain | $\mathrm{A}_{\mathrm{vo}}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{O}}= \pm 10 \mathrm{~V} \\ & \mathrm{R}_{\mathrm{L}}=10 \mathrm{k} \Omega \\ & \mathrm{R}_{\mathrm{L}}=2 \mathrm{k} \Omega \\ & \hline \end{aligned}$ | $\begin{aligned} & 750 \\ & 400 \end{aligned}$ | $\begin{aligned} & 1600 \\ & 800 \end{aligned}$ |  | $\mathrm{V} / \mathrm{mV}$ |
| INPUT VOLTAGE RANGE* | IVR |  | $\pm 11$ | $\pm 12$ |  | V |
| OUTPUT VOLTAGE SWING | $\mathrm{V}_{\mathrm{O}}$ | $\mathrm{R}_{\mathrm{L}} \geq 2 \mathrm{k} \Omega$ | $\pm 12$ | $\pm 13$ |  | V |
| COMMON-MODE REJECTION | CMR | $\mathrm{V}_{\mathrm{CM}}= \pm 11 \mathrm{~V}$ | 100 | 120 |  | dB |
| POWER SUPPLY REJECTION RATIO | PSRR | $\mathrm{V}_{\mathrm{S}}= \pm 4.5 \mathrm{~V}$ to $\pm 18 \mathrm{~V}$ |  | 1.0 | 5.6 | $\mu \mathrm{V} / \mathrm{V}$ |
| SUPPLY CURRENT <br> (All Amplifiers) | $\mathrm{I}_{\mathrm{SY}}$ | No Load | - | 9.2 | 11 | mA |

*Guaranteed by CMR test

ELECTRICAL CHARACTERISTICS
(at $V_{S}= \pm 15 \mathrm{~V},-25^{\circ} \mathrm{C} \leq \mathrm{T}_{\mathrm{A}} \leq 85^{\circ} \mathrm{C}$ for OP470E/OP470EF, $-40^{\circ} \mathrm{C} \leq \mathrm{T}_{\mathrm{A}} \leq 85^{\circ} \mathrm{C}$ for OP470G, unless otherwise noted.)

| Parameter | Symbol | Conditions | OP470E |  |  | OP470F |  |  | OP470G |  |  | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | Min | Typ | Max | Min | Typ | Max | Min |  | Max |  |
| INPUT OFFSET voltage | $\mathrm{V}_{\text {OS }}$ |  |  | 0.12 | 0.5 |  | 0.24 | 1.0 |  | 0.5 | 1.5 | mV |
| AVERAGE INPUT Offset Voltage Drift | $\mathrm{TCV}_{\text {OS }}$ |  |  | 0.4 | 2 |  | 0.6 | 4 |  | 2 |  | $\mu \mathrm{V} /{ }^{\circ} \mathrm{C}$ |
| INPUT OFFSET CURRENT | $\mathrm{I}_{\mathrm{OS}}$ | $\mathrm{V}_{\mathrm{CM}}=0 \mathrm{~V}$ |  | 4 | 20 |  | 7 | 40 |  | 20 | 50 | nA |
| INPUT BIAS CURRENT | $\mathrm{I}_{\mathrm{B}}$ | $\mathrm{V}_{\mathrm{CM}}=0 \mathrm{~V}$ |  | 11 | 50 |  | 20 | 70 |  | 40 | 75 | nA |
| LARGE-SIGNAL <br> Voltage Gain | $\mathrm{A}_{\mathrm{vo}}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{O}}= \pm 10 \mathrm{~V} \\ & \mathrm{R}_{\mathrm{L}}=10 \mathrm{k} \Omega \\ & \mathrm{R}_{\mathrm{L}}=2 \mathrm{k} \Omega \\ & \hline \end{aligned}$ | $\begin{aligned} & 800 \\ & 400 \end{aligned}$ | $\begin{aligned} & 1800 \\ & 900 \end{aligned}$ |  | $\begin{aligned} & 600 \\ & 300 \end{aligned}$ | $\begin{aligned} & 1400 \\ & 700 \end{aligned}$ |  | $\begin{aligned} & 600 \\ & 300 \end{aligned}$ | $\begin{aligned} & 1500 \\ & 800 \end{aligned}$ |  | $\mathrm{V} / \mathrm{mV}$ |
| INPUT VOLTAGE RANGE* | IVR |  | $\pm 11$ | $\pm 12$ |  | $\pm 11$ | $\pm 12$ |  | $\pm 11$ | $\pm 12$ |  | V |
| OUTPUT VOLTAGE SWING | $\mathrm{V}_{\mathrm{O}}$ | $\mathrm{R}_{\mathrm{L}} \geq 2 \mathrm{k} \Omega$ | $\pm 12$ | $\pm 13$ |  | $\pm 12$ | $\pm 13$ |  | $\pm 12$ | $\pm 13$ |  | V |
| COMMON-MODE REJECTION | CMR | $\mathrm{V}_{\mathrm{CM}}= \pm 11 \mathrm{~V}$ | 100 | 120 |  | 90 | 115 |  | 90 | 110 |  | dB |
| POWER SUPPLY REJECTION RATIO | PSRR | $\mathrm{V}_{\mathrm{S}}= \pm 4.5 \mathrm{~V}$ to $\pm 18 \mathrm{~V}$ |  | 0.7 | 5.6 |  | 1.8 | 10 |  | 1.8 | 10 | $\mu \mathrm{V} / \mathrm{V}$ |
| SUPPLY CURRENT <br> (All Amplifiers) | $\mathrm{I}_{\mathrm{SY}}$ | No Load | - | 9.2 | 11 | - | 9.2 | 11 | - | 9.3 | 11 | mA |

[^1]
## OP470-SPECIFICATIONS

WAFER TEST LIMITS ata $_{\mathrm{s}}= \pm 15 \mathrm{I}, 255^{\circ}$, uness stienemise noted)

| Parameter | Symbol | Conditions | OP470GBC Limit | Unit |
| :---: | :---: | :---: | :---: | :---: |
| INPUT OFFSET VOLTAGE | $\mathrm{V}_{\text {OS }}$ |  | 0.8 | mV Max |
| INPUT OFFSET CURRENT | $\mathrm{I}_{\text {OS }}$ | $\mathrm{V}_{\mathrm{CM}}=0 \mathrm{~V}$ | 20 | nA Max |
| INPUT BIAS CURRENT | $\mathrm{I}_{\mathrm{B}}$ | $\mathrm{V}_{\mathrm{CM}}=0 \mathrm{~V}$ | 50 | nA Min |
| LARGE-SIGNAL <br> Voltage Gain | $\mathrm{A}_{\mathrm{Vo}}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{O}}= \pm 10 \mathrm{~V} \\ & \mathrm{R}_{\mathrm{L}}=10 \mathrm{k} \Omega \\ & \mathrm{R}_{\mathrm{L}}=2 \mathrm{k} \Omega \\ & \hline \end{aligned}$ | $\begin{aligned} & 800 \\ & 400 \end{aligned}$ | V/mV Min |
| INPUT VOLTAGE RANGE* | IVR |  | $\pm 11$ | V Min |
| OUTPUT VOLTAGE SWING | $\mathrm{V}_{\mathrm{O}}$ | $\mathrm{R}_{\mathrm{L}} \geq 2 \mathrm{k} \Omega$ | $\pm 12$ | V Min |
| COMMON-MODE REJECTION | CMR | $\mathrm{V}_{\mathrm{CM}}= \pm 11 \mathrm{~V}$ | 100 | dB |
| POWER SUPPLY <br> REJECTION RATIO | PSRR | $\mathrm{V}_{\mathrm{S}}= \pm 4.5 \mathrm{~V}$ to $\pm 18 \mathrm{~V}$ | 5.6 | $\mu \mathrm{V} / \mathrm{V}$ Max |
| SUPPLY CURRENT <br> (All Amplifiers) | $\mathrm{I}_{\text {SY }}$ | No Load | 11 | mA Max |

NOTE
*Guaranteed by CMR test
Electrical tests are performed at wafer probe to the limits shown. Due to variations in assembly methods and normal yield loss, yield after packaging is not guaranteed for standard product dice. Consult factory to negotiate specifications based on dice lot qualification through sample lot assembly and testing.

| ABSOLUTE MAXIMUM RATINGS ${ }^{1}$ |  |
| :---: | :---: |
| Supply Voltage | $\pm 18 \mathrm{~V}$ |
| Differential Input Voltage ${ }^{2}$ | $\pm 1.0 \mathrm{~V}$ |
| Differential Input Current ${ }^{2}$ | $\pm 25 \mathrm{~mA}$ |
| Input Voltage | Supply Voltage |
| Output Short-Circuit Duration | Continuous |
| Storage Temperature Range |  |
| P, Y Package | $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ |
| Lead Temperature Range (Soldering 60 sec ) | $.300^{\circ} \mathrm{C}$ |
| Junction Temperature ( $\mathrm{T}_{\mathrm{j}}$ ) | $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ |
| Operating Temperature Range |  |
| OP470A | $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |
| OP470E, OP470F | $-25^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |
| OP470G | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |

ORDERING GUIDE

| $\mathbf{T}_{\mathbf{A}}=\mathbf{2 5}^{\circ} \mathbf{C}$ |  |  |  |
| :--- | :--- | :--- | :--- |
|  | Package Options |  |  |
| Operating <br> Temperature <br> Range |  |  |  |
| 400 | Cerdip |  | Plastic |

*Not for new design; obsolete April 2002.
For military processed devices, please refer to the standard Microcircuit Drawing (SMD) available at www.dscc.dla.mil/programs/milspec/default.asp

| SMD Part Number | ADI Equivalent |
| :--- | :--- |
| 59628856501 CA | OP470AYMDA |
| 596288565012 A | OP470ARCMDA |
| $596288565013 A^{*}$ | OP470ATCMDA |

[^2]| Package Type | $\boldsymbol{\theta}_{\mathbf{J A}}{ }^{\mathbf{3}}$ | $\boldsymbol{\theta}_{\mathrm{JC}}$ | Unit |
| :--- | :--- | :---: | :---: |
| 14-Lead Hermetic DIP(Y) | 94 | 10 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| 14-Lead Plastic DIP(P) | 76 | 33 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| 16-Lead SOIC (S) | 88 | 23 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |

NOTES
${ }^{1}$ Absolute Maximum Ratings apply to both DICE and packaged parts, unless otherwise noted.
${ }^{2}$ The OP470's inputs are protected by back-to-back diodes. Current limiting resistors are not used in order to achieve low noise performance. If differential voltage exceeds $\pm 1.0 \mathrm{~V}$, the input current should be limited to $\pm 25 \mathrm{~mA}$.
${ }^{3} \theta_{\mathrm{JA}}$ is specified for worst case mounting conditions, i.e., $\theta_{\mathrm{JA}}$ is specified for device in socket for TO, CerDIP, PDIP, packages; $\theta_{\mathrm{JA}}$ is specified for device soldered to printed circuit board for SOIC packages.


Figure 1. Dice Characteristics

## CAUTION

ESD (electrostatic discharge) sensitive device. Electrostatic charges as high as 4000 V readily accumulate on the human body and test equipment and can discharge without detection. Although the OP470 features proprietary ESD protection circuitry, permanent damage may occur on devices subjected to high energy electrostatic discharges. Therefore, proper ESD precautions are recommended to avoid performance degradation or loss of functionality.

## OP470-Typical Performance Characteristics



TPC 1. Voltage Noise Density vs. Frequency


TPC 4. Current Noise Density vs. Frequency


TPC 7. Input Bias Current vs. Temperature


TPC 2. Voltage Noise Density vs. Supply Voltage


TPC 5. Input Offset Voltage vs. Temperature


TPC 8. Input Offset Current vs. Temperature


TPC 3. 0.1 Hz to 10 Hz Noise


TPC 6. Warm-Up Offset Voltage Drift


TPC 9. Input Bias Current vs. Common-Mode Voltage

$$
\begin{array}{|r|}
\hline \\
\text { OP470 } \\
\hline
\end{array}
$$



TPC 10. CMR vs. Frequency


TPC 13. PSR vs. Frequency


TPC 16. Open-Loop Gain, Phase Shift vs. Frequency


TPC 11. Total Supply Current vs. Supply Voltage


TPC 14. Open-Loop Gain vs. Frequency


TPC 17. Open-Loop Gain vs. Supply Voltage


TPC 12. Total Supply Current vs. Supply Voltage


TPC 15. Closed-Loop Gain vs. Frequency


TPC 18. Gain-Bandwidth Product, Phase Margin vs. Temperature


TPC 19. Maximum Output Swing vs. Frequency


TPC 22. Output Impedance vs. Frequency


TPC 25. Total Harmonic Distortion vs. Frequency


TPC 20. Maximum Output Voltage vs. Load Resistance


TPC 23. Slew Rate vs. Temperature


TPC 26. Large-Signal Transient Response


TPC 21. Small-Signal Overshoot vs. Capacitive Load


TPC 24. Channel Separation vs. Frequency


TPC 27. Small-Signal Transient Response


Figure 2. Channel Separation Test Circuit


Figure 3. Burn-In Circuit

## APPLICATIONS INFORMATION

## Voltage and Current Noise

The OP470 is a very low-noise quad op amp, exhibiting a typical voltage noise of only $3.2 \mathrm{nV} \sqrt{\mathrm{Hz}} @ 1 \mathrm{kHz}$. The exceptionally low-noise characteristics of the OP470 are in part achieved by operating the input transistors at high collector currents since the voltage noise is inversely proportional to the square root of the collector current. Current noise, however, is directly proportional to the square root of the collector current. As a result, the outstanding voltage noise performance of the OP470 is gained at the expense of current noise performance, which is typical for low noise amplifiers.
To obtain the best noise performance in a circuit, it is vital to understand the relationship between voltage noise ( $e_{n}$ ), current noise ( $i_{n}$ ), and resistor noise ( $e_{t}$ ).

## TOTAL NOISE AND SOURCE RESISTANCE

The total noise of an op amp can be calculated by:

$$
E_{n}=\sqrt{\left(e_{n}\right)^{2}+\left(i_{n} R_{S}\right)^{2}+\left(e_{t}\right)^{2}}
$$

where:
$\mathrm{E}_{\mathrm{n}}=$ total input referred noise
$\mathrm{e}_{\mathrm{n}}=$ up amp voltage noise
$\mathrm{i}_{\mathrm{n}}=\mathrm{op}$ amp current noise
$e_{t}=$ source resistance thermal noise
$\mathrm{R}_{\mathrm{S}}=$ source resistance

The total noise is referred to the input and at the output would be amplified by the circuit gain. Figure 4 shows the relationship between total noise at 1 kHz and source resistance. For $\mathrm{R}_{\mathrm{S}}<1 \mathrm{k} \Omega$ the total noise is dominated by the voltage noise of the OP470. As $R_{S}$ rises above $1 \mathrm{k} \Omega$, total noise increases and is dominated by resistor noise rather than by voltage or current noise of the OP470. When $\mathrm{R}_{\mathrm{S}}$ exceeds $20 \mathrm{k} \Omega$, current noise of the OP470 becomes the major contributor to total noise.
Figure 5 also shows the relationship between total noise and source resistance, but at 10 Hz . Total noise increases more quickly than shown in Figure 4 because current noise is inversely proportional to the square root of frequency. In Figure 5, current noise of the OP470 dominates the total noise when $R_{S}>5 \mathrm{k} \Omega$.
From Figures 4 and 5 it can be seen that to reduce total noise, source resistance must be kept to a minimum. In applications with a high source resistance, the OP400, with lower current noise than the OP470, will provide lower total noise.


Figure 4. Total Noise vs. Source Resistance (Including Resistor Noise) at 1 kHz


Figure 5. Total Noise vs. Source Resistance (Including Resistor Noise) at 10 Hz

## OP470

Figure 6 shows peak-to-peak noise versus source resistance over the 0.1 Hz to 10 Hz range. Once again, at low values of $\mathrm{R}_{\mathrm{S}}$, the voltage noise of the OP470 is the major contributor to peak-to-peak noise with current noise the major contributor as $\mathrm{R}_{\mathrm{S}}$ increases. The crossover point between the OP470 and the OP400 for peak-to-peak noise is at $\mathrm{R}_{\mathrm{S}}=17 \mathrm{k} \Omega$.
The OP471 is a higher speed version of the OP470, with a slew rate of $8 \mathrm{~V} / \mu \mathrm{s}$. Noise of the OP471 is only slightly higher than the OP470. Like the OP470, the OP471 is unity-gain stable.


Figure 6. Peak-To-Peak Noise ( 0.1 Hz to 10 Hz ) vs. Source Resistance (Includes Resistor Noise)
For reference, typical source resistances of some signal sources are listed in Table I.


Figure 7. Peak-To-Peak Voltage Noise Test Circuit ( 0.1 Hz to 10 Hz )
4. The test time to measure 0.1 Hz to 10 Hz noise should not exceed 10 seconds. As shown in the noise-tester frequency-response curve of Figure 8, the 0.1 Hz corner is defined by only one pole. The test time of 10 seconds acts as an additional pole to eliminate noise contribution from the frequency band below 0.1 Hz .
5. A noise-voltage-density test is recommended when measuring noise on a large number of units. A 10 Hz noise voltage-density measurement will correlate well with a 0.1 Hz to 10 Hz peak-to-peak noise reading, since both results are determined by the white noise and the location of the $1 / \mathrm{f}$ corner frequency.
6. Power should be supplied to the test circuit by well bypassed low noise supplies, e.g. batteries. These will minimize output noise introduced via the amplifier supply pins.


Figure 8. 0.1 Hz to 10 Hz Peak-to-Peak Voltage Noise Test Circuit Frequency Response

## NOISE MEASUREMENT—NOISE VOLTAGE DENSITY

The circuit of Figure 9 shows a quick and reliable method of measuring the noise voltage density of quad op amps. Each individual amplifier is series-connected and is in unity-gain, save the final amplifier which is in a noninverting gain of 101 . Since the ac noise voltages of each amplifier are uncorrelated, they add in rms fashion to yield:

The OP470 is a monolithic device with four identical amplifiers. The noise voltage density of each individual amplifier will match, giving:

$$
e_{O U T}=101\left(\sqrt{4 e_{n}^{2}}\right)=101\left(2 e_{n}\right)
$$

## NOISE MEASUREMENT—CURRENT NOISE DENSITY

The test circuit shown in Figure 10 can be used to measure current noise density. The formula relating the voltage output to current noise density is:

$$
i_{n}=\frac{\sqrt{\left(\frac{\theta_{n O U T}}{G}\right)^{2}-(40 n V / \sqrt{H z})^{2}}}{R_{S}}
$$

where:
$\mathrm{G}=$ gain of 10000
$\mathrm{R}_{\mathrm{S}}=100 \mathrm{k} \Omega$ source resistance


Figure 10. Current Noise Density Test Circuit

$$
e_{O U T}=101\left(\sqrt{e_{n A}^{2}+e_{n B}^{2}+e_{n C}^{2}+e_{n D}^{2}}\right)
$$



Figure 9. Noise Voltage Density Test Circuit

## CAPACITIVE LOAD DRIVING AND POWER SUPPLY CONSIDERATIONS

The OP470 is unity-gain stable and is capable of driving large capacitive loads without oscillating. Nonetheless, good supply bypassing is highly recommended. Proper supply bypassing reduces problems caused by supply line noise and improves the capacitive load driving capability of the OP470.
In the standard feedback amplifier, the op amp's output resistance combines with the load capacitance to form a low pass filter that adds phase shift in the feedback network and reduces stability. A simple circuit to eliminate this effect is shown in Figure 11. The added components, C1 and R3, decouple the amplifier from the load capacitance and provide additional stability. The values of C 1 and R 3 shown in Figure 11 are for a load capacitance of up to 1000 pF when used with the OP470.


Figure 11. Driving Large Capacitive Loads
In applications where the OP470's inverting or noninverting inputs are driven by a low source impedance (under $100 \Omega$ ) or connected to ground, if $\mathrm{V}+$ is applied before $\mathrm{V}-$, or when V is disconnected, excessive parasitic currents will flow. Most applications use dual tracking supplies and with the device supply pins properly bypassed, power-up will not present a problem. A source resistance of at least $100 \Omega$ in series with all inputs (Figure 11) will limit the parasitic currents to a safe level if V - is disconnected. It should be noted that any source resistance, even $100 \Omega$, adds noise to the circuit. Where noise is required to be kept at a minimum, a germanium or Schottky diode can be used to clamp the V - pin and eliminate the parasitic current flow instead of using series limiting resistors. For most applications, only one diode clamp is required per board or system.

## UNITY-GAIN BUFFER APPLICATIONS

When $\mathrm{Rf} \leq 100 \Omega$ and the input is driven with a fast, large signal pulse(> 1 V ), the output waveform will look as shown in Figure 12.


Figure 12. Pulsed Operation
During the fast feedthrough-like portion of the output, the input protection diodes effectively short the output to the input, and a current, limited only by the output short-circuit protection, will be drawn by the signal generator. With $\operatorname{Rf} \leq 500 \Omega$, the output is capable of handling the current requirements (IL $<20 \mathrm{~mA}$ at 10 V ); the amplifier will stay in its active mode and a smooth transition will occur.
When $\mathrm{Rf}>3 \mathrm{k} \Omega$, a pole created by Rf and the amplifier's input capacitance ( 2 pF ) creates additional phase shift and reduces phase margin. A small capacitor ( 20 pF to 50 pF ) in parallel with Rf helps eliminate this problem.

## APPLICATIONS

## Low Noise Amplifier

A simple method of reducing amplifier noise by paralleling amplifiers is shown in Figure 13. Amplifier noise, depicted in Figure 14, is around $2 \mathrm{nV} / \sqrt{\mathrm{Hz}} @ 1 \mathrm{kHz}$ (R.T.I.). Gain for each paralleled amplifier and the entire circuit is 1000 . The $200 \Omega$ resistors limit circulating currents and provide an effective output resistance of $50 \Omega$. The amplifier is stable with a 10 nF capacitive load and can supply up to 30 mA of output drive.


Figure 13. Low Noise Amplifier


Figure 14. Noise Density of Low Noise Amplifier, $G=1000$

## DIGITAL PANNING CONTROL

Figure 15 uses a DAC-8408, quad 8-bit DAC to pan a signal between two channels. The complementary DAC current outputs two of the DAC-8408's four DACs drive current-to-voltage converters built from a single quad OP470. The amplifiers have complementary outputs with the amplitudes dependent upon the digital code applied to the DAC. Figure 16 shows the complementary outputs for a 1 kHz input signal and digital ramp applied to the DAC data inputs. Distortion of the digital panning control is less than $0.01 \%$.


Figure 16. Digital Panning Control Output
Gain error due to the mismatching between the internal DAC ladder resistors and the current-to-voltage feedback resistors is eliminated by using feedback resistors internal to the DAC. Of the four DACs available in the DAC-8408, only two DACs, A and C, actually pass a signal. DACs $B$ and $D$ are used to provide the additional feedback resistors needed in the circuit. If the VREFB and VREFD inputs remain unconnected, the current-to-voltage converters using RFBB and RFBD are unaffected by digital data reaching DACs B and D.


Figure 15. Digital Panning Control Circuit

## OP470

## SQUELCH AMPLIFIER

The circuit of Figure 17 is a simple squelch amplifier that uses a FET switch to cut off the output when the input signal falls below a preset limit.
The input signal is sampled by a peak detector with a time constant set by C 1 and R6. When the output of the peak detector (Vp), falls below the threshold voltage, (VTH), set by R8, the comparator formed by op amp C switches from V- to V+. This drives the gate of the N-channel FET high, turning it ON, reducing the gain of the inverting amplifier formed by op amp A to zero.


Figure 17. Squelch Amplifier

FIVE-BAND LOW-NOISE STEREO GRAPHIC EQUALIZER
The graphic equalizer circuit shown in Figure 18 provides 15 dB of boost or cut over a 5-band range. Signal-to-noise ratio over a 20 kHz bandwidth is better than 100 dB referred to a 3 V rms input. Larger inductors can be replaced by active inductors but this reduces the signal-to-noise ratio.


Figure 18. Five-Band Low Noise Graphic Equalizer

## OUTLINE DIMENSIONS

14-Lead Ceramic Dip-Glass Hermetic Seal [CERDIP] (Q-14)
Dimensions shown in inches and (millimeters)


CONTROLLING DIMENSIONS ARE IN INCHES; MILLIMETERS DIMENSIONS (IN PARENTHESES) ARE ROUNDED-OFF INCH EQUIVALENTS FOR REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN

14-Lead Plastic Dual-in-Line Package [PDIP] (N-14)
Dimensions shown in inches and (millimeters)


CONTROLLING DIMENSIONS ARE IN INCH; MILLIMETERS DIMENSIONS (IN PARENTHESES) ARE ROUNDED-OFF MILLIMETER EQUIVALENTS FOR REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN

## 16-Lead Standard Small Outline Package [SOIC] <br> Wide Body <br> (RW-16)

Dimensions shown in millimeters and (inches)

ADV611/ADV612
Revision History
Location Page
10/02-Data Sheet changed from REV. A to REV. B.
Edits to 16-Lead SOIC ..... 1
Edits to ELECTRICAL CHARACTERISTICS ..... 3
Edits to ABSOLUTE MAXIMUM RATINGS ..... 5
Updated OUTLINE DIMENSIONS ..... 15
4/02—Data Sheet changed from REV. 0 to REV. A.
28-Lead LCC (RC-Suffix) deleted ..... 1
28-Lead LCC (TC-Suffix) deleted ..... 1
Edits to ABSOLUTE MAXIMUM RATINGS ..... 4
Edits to ORDERING GUIDE ..... 4
Edits to PACKAGE TYPE ..... 4

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